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Renesas Electronics website: http://www.renesas.com

April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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# MOS FIELD EFFECT TRANSISTOR 2SK4075

# SWITCHING N-CHANNEL POWER MOS FET

#### **DESCRIPTION**

The 2SK4075 is N-channel MOS FET designed for high current switching applications.

#### ORDERING INFORMATION

PART NUMBER	LEAD PLATING	PACKING	PACKAGE
2SK4075-ZK-E1-AY	Pure Sn (Tin)	Tape	TO-2 <mark>52</mark> (MP-3ZK)
2SK4075-ZK-E2-AY		2500 p/reel	typ. 0.27 g

#### **FEATURES**

· Low on-state resistance

 $R_{DS(on)1} = 6.7 \text{ m}\Omega \text{ MAX.} \text{ (Vgs} = 10 \text{ V, I}_D = 30 \text{ A)}$ 

 $R_{DS(on)2} = 10 \text{ m}\Omega \text{ MAX}. \text{ (Vgs} = 4.5 \text{ V, I}_D = 15 \text{ A})$ 

• Low Ciss: Ciss = 2900 pF TYP.

• Logic level drive type





#### ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (Vgs = 0 V)	VDSS	40	V
Gate to Source Voltage (Vps = 0 V)	Vgss	±20	V
Drain Current (DC) (Tc = 25°C)	I <sub>D(DC)</sub>	±60	Α
Drain Current (pulse) Note1	ID(pulse)	±180	Α
Total Power Dissipation (Tc = 25°C)	P <sub>T1</sub>	52	W
Total Power Dissipation (T <sub>A</sub> = 25°C)	P <sub>T2</sub>	1.0	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C
Single Avalanche Current Note2	las	28	Α
Single Avalanche Energy Note2	Eas	78	mJ

**Notes 1.** PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1%

**2.** Starting T<sub>ch</sub> = 25°C, V<sub>DD</sub> = 20 V, R<sub>G</sub> = 25  $\Omega$ , V<sub>GS</sub> = 20  $\rightarrow$  0 V, L = 100  $\mu$ H

#### THERMAL RESISTANCE

Channel to Case Thermal Resistance	Rth(ch-C)	2.4	°C/W
Channel to Ambient Thermal Resistance	Rth(ch-A)	125	°C/W

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#### **ELECTRICAL CHARACTERISTICS (TA = 25°C)**

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> = 40 V, V <sub>GS</sub> = 0 V			1	μΑ
Gate Leakage Current	Igss	V <sub>GS</sub> = ±20 V, V <sub>DS</sub> = 0 V			±100	nA
Gate Cut-off Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	1.5	2.0	2.5	V
Forward Transfer Admittance Note	yfs	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 15 A	9.3			S
Drain to Source On-state Resistance Note	RDS(on)1	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 30 A		5.2	6.7	mΩ
	RDS(on)2	V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 15 A		7.2	10	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> = 10 V		2900		pF
Output Capacitance	Coss	V <sub>G</sub> S = 0 V		450		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		293		pF
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> = 20 V		18		ns
Rise Time	tr	I <sub>D</sub> = 30 A		16		ns
Turn-off Delay Time	td(off)	V <sub>GS</sub> = 10 V		54		ns
Fall Time	tf	R <sub>G</sub> = 0 Ω		9		ns
Total Gate Charge	Q <sub>G</sub>	V <sub>DD</sub> = 32 V		54		nC
Gate to Source Charge	Qgs	V <sub>GS</sub> = 10 V		11		nC
Gate to Drain Charge	Q <sub>GD</sub>	I <sub>D</sub> = 60 A		15		nC
Body Diode Forward Voltage Note	V <sub>F(S-D)</sub>	IF = 60 A, VGS = 0 V		0.9	1.5	V
Reverse Recovery Time	trr	IF = 60 A, VGS = 0 V		33		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		33		nC

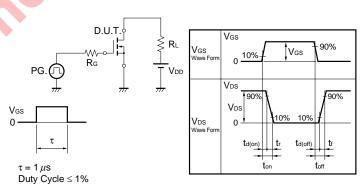
Note Pulsed

#### TEST CIRCUIT 1 AVALANCHE CAPABILITY

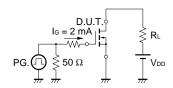
# $V_{GS} = 20 \rightarrow 0 \text{ V}$ $V_{DD}$ $V_{DD}$

-Starting Tch

#### TEST CIRCUIT 2 SWITCHING TIME

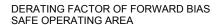


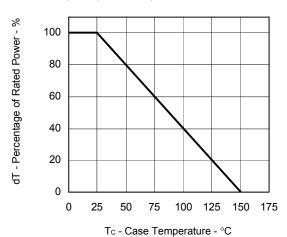
#### **TEST CIRCUIT 3 GATE CHARGE**



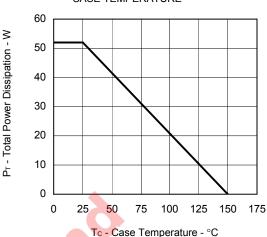
Ip - Drain Current - A

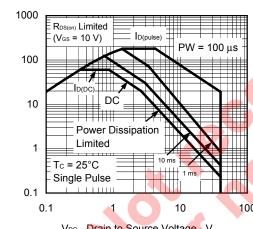
#### TYPICAL CHARACTERISTICS (TA = 25°C)



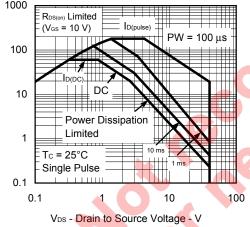


#### TOTAL POWER DISSIPATION vs. CASE TEMPERATURE

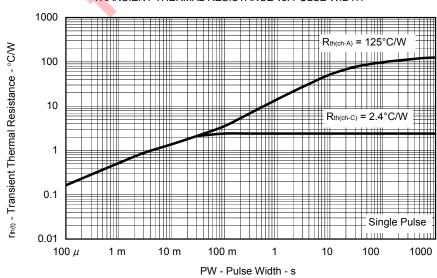




#### FORWARD BIAS SAFE OPERATING AREA



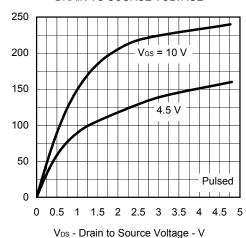
#### TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



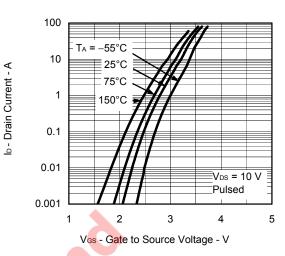
lo - Drain Current - A

VGS(off) - Gate Cut-off Voltage - V

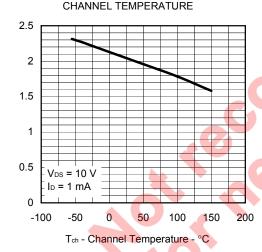




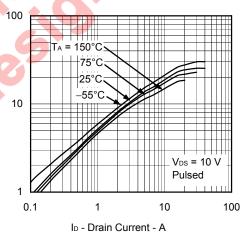
#### FORWARD TRANSFER CHARACTERISTICS



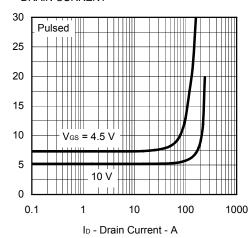
GATE CUT-OFF VOLTAGE vs.



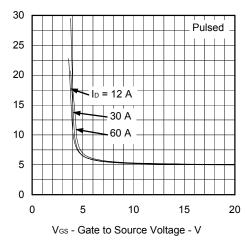
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATERESISTANCE vs. GATE TO SOURCE VOLTAGE



R<sub>DS(m)</sub> - Drain to Source On-state Resistance - mΩ

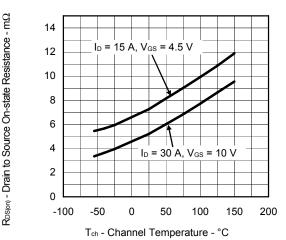
| yfs | - Forward Transfer Admittance -

R<sub>DS(cn)</sub> - Drain to Source On-state Resistance - mΩ

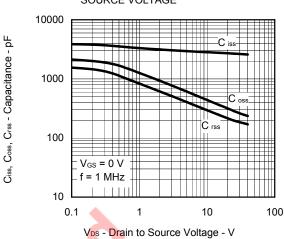
ta(on), tr, ta(off), tr - Switching Time - ns

I - Diode Forward Current - A

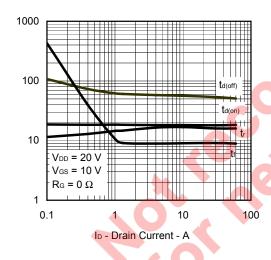
# DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



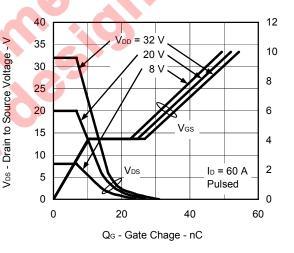
## CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



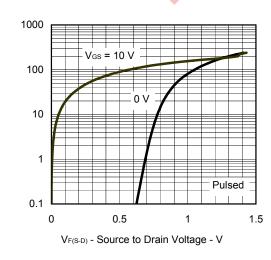
#### SWITCHING CHARACTERISTICS



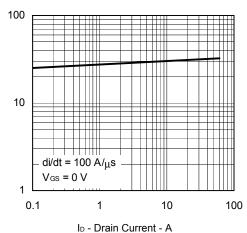
#### DYNAMIC INPUT/OUTPUT CHARACTERISTICS



#### SOURCE TO DRAIN DIODE FORWARD VOLTAGE



REVERSE RECOVERY TIME vs. DRAIN CURRENT

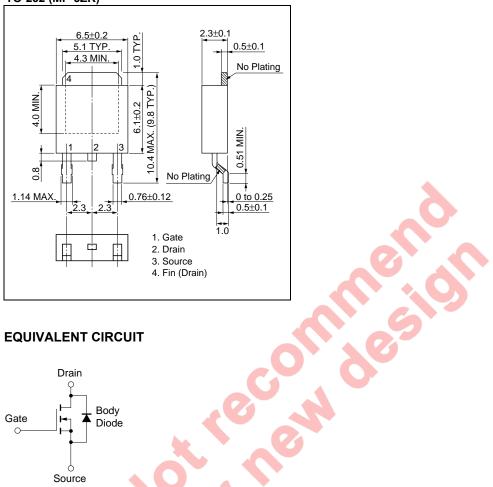


Ves - Gate to Source Voltage - V

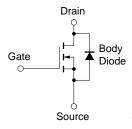
trr - Reverse Recovery Time - ns

#### **PACKAGE DRAWING (Unit: mm)**

#### TO-252 (MP-3ZK)



#### **EQUIVALENT CIRCUIT**

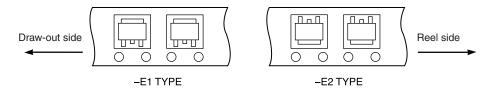


Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

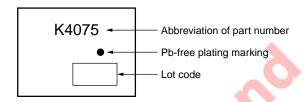


#### TAPE INFORMATION

There are two types (-E1, -E2) of taping depending on the direction of the device.



#### MARKING INFORMATION



#### RECOMMENDED SOLDERING CONDITIONS

The 2SK4075 should be soldered and mounted under the following recommended conditions.

For soldering methods and conditions other than those recommended below, please contact an NEC Electronics sales representative.

For technical information, see the following website.

Semiconductor Device Mount Manual (http://www.necel.com/pkg/en/mount/index.html)

Soldering Method	Soldering Conditions	Recommended Condition Symbol
Infrared reflow	Maximum temperature (Package's surface temperature): 260°C or below Time at maximum temperature: 10 seconds or less Time of temperature higher than 220°C: 60 seconds or less Preheating time at 160 to 180°C: 60 to 120 seconds Maximum number of reflow processes: 3 times	IR60-00-3
Partial heating	Maximum chlorine content of rosin flux (percentage mass): 0.2% or less  Maximum temperature (Pin temperature): 350°C or below  Time (per side of the device): 3 seconds or less  Maximum chlorine content of rosin flux: 0.2% (wt.) or less	P350

Caution Do not use different soldering methods together (except for partial heating).

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